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Investigated Structure-Property Relationships of Thiadiazoloquinoxaline-Based Copolymer Semiconductors via Molecular Engineering

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Six thiadiazoloquinoxaline (TQ) based copolymers (**P1-P6**) have been synthesized using Stille coupling reaction upon varying donor moieties, substitution positions and architectures of polymer side chains. UV-vis-NIR absorption spectra indicated that all of these polymers exhibited low optical bandgaps from 0.96 to 0.75 eV. The electron affinities of these six polymers with values from -3.92 to -3.99 eV slightly changed due to the contribution of the same TQ core. However, the ionization potentials were tuned from -4.95 eV in **P1** to -5.28 eV in **P3** by introducing different donors. Comparing polymers **P1-P4** with different donor parts, two dimensional wide-angle X-ray scattering measurements implied that **P4** had a higher crystallinity because its coherence length (5.8 nm) was 2-3 times higher than those of **P1-P3** (1.7-2.9 nm). This led to a best field-effect hole mobility of 0.1 cm² V⁻¹ s⁻¹ for **P4** in the four polymers. The polymers **P4-P6** had identical molecular formulas of side chains but significant differences in device performance. In comparison with **P4**, the two linear alkyl chains were moved onto head to head positions of bithiophene in **P5**, resulting in a hole mobility of only 0.007 cm² V⁻¹ s⁻¹. However, a pair of 2-decyl-tetradecyl alkyl chains was grafted onto thiophene units adjacent to the TQ core in **P6**, leading to a highest hole mobility up to 0.24 cm² V⁻¹ s⁻¹ in this series of polymers.

Introduction

Donor-acceptor (D-A) alternating π -conjugated copolymers have attracted attention in organic light-emitting diodes (OLEDs), polymer solar cells (PSCs) and organic field-effect transistors (OFETs).¹⁻⁴ Combination of different D and A units can easily tune optoelectronic properties, thereby also affect the device performances of the D-A copolymers. Investigation of the structureproperty relationships of such polymers is an important method to understand and design high-performance optoelectronic materials.^{5, 6} Some strong acceptors have been reported, like diketopyrrolopyrrole (DPP),⁷⁻⁹ naphthalene diimide (NDI),¹⁰⁻¹² benzobisthiadiazole (BBT)¹³ and isoindigo (IID).^{14, 15} Thiadiazoloquinoxalines (TQs) possess outstanding electron affinity and variable chemical structures,¹⁶⁻²⁰ therefore becoming a class of important building blocks for polymer semiconductors. However, TQ polymers usually exhibit relatively low FET performances due to their disorder in thin films.²¹⁻²⁵ It is therefore necessary to systematically study the structure and charge transport correlation of TO polymers in order to identify the essential parameters for highly ordered microstructures which could further improve their charge carrier mobility.

A TQ derivative, 6,7-diphenyl-[1,2,5]thiadiazolo[3,4g]quinoxaline (**PTQ**, Figure 1), has been widely investigated as an acceptor for creating polymer semiconductors, because of its ease of synthesis and good charge carrier mobilities compared to other TQ derivatives.²⁶⁻²⁸ A D-A-D style of **PTQ**, 6,7-diphenyl-4,9di(thiophen-2-yl)-[1,2,5]thiadiazolo[3,4-g]quinoxaline (**TQ-2T**, Figure 1) was also reported by modifying the **PTQ** core with two flanking thiophenes, which can offer more alkylation positions to improve their solubility.^{24, 29-32} In view of the lack of study on the structure-property relationships of TQ polymers, we herein investigate this topic based on **TQ-2T** polymers from two crucial aspects. Firstly, introduction of unsubstituted donor units with different electron-donating ability which enhances the backbone coplanarity of the **TQ-2T** polymers and potentially leads to ordered arrangement in the polymer films. Secondly, tuning substitution positions and architectures of the alkyl chains in the polymer repeat units improves the polymer solubility, the molecular weights as well as the device performance.



Figure 1. Structures of PTQ and TQ-2T reported in literature.

In this work, we report six new **TQ-2T** based copolymers **P1-P6** (Figure 2). Different unsubstituted donors, namely, thiophene (**T**), thieno[3, 2-b]thiophene (**TT**), benzo[1,2-b:4,5-b']dithiophene (**BDT**) and 2,2'-bithiophene (**BT**) were introduced alternatingly with **TQ-2T** providing the corresponding polymers **P1-P4**. These donor units are expected to decrease the torsion angles along the polymer backbone. **P5** was designed and synthesized for comparison with **P4** by varying the substitution positions of the alkyl chains. This design aims to improve the solubility and molecular weight but at the cost of sacrificing coplanarity of the polymer main chain. In order to possess better solubility, higher molecular weight, and similar backbone coplanarity in comparison with **P4**, the architecture and the bulkiness of the alkyl chains were modified by replacing four

dodecyl linear chains in P4 with a pair of 2-decyl-tetradecyl alkyl

chains to obtain P6. The optical, electrochemical, charge transport and self-organization properties of these copolymers were

comparatively characterized and studied in details.



Figure 2. Structures of P1-P6 synthesized and studied in this work.

Results and discussion

Synthesis and Characterization



Scheme 1. Synthetic routes for TQ-2T-based polymers.

The synthesis of the six polymers is outlined in Scheme 1. Monomer **3** was obtained by condensation between 4,7-bis(4-dodecylthiophen-2-yl)benzo[c][1,2,5]thiadiazole-5,6-diamine (1) and 1,2-bis(4-dodecylphenyl)ethane-1,2-dione (2), and then it was dibrominated to produce compound 4 for polymerization. Compounds 7 and 12 were obtained using a procedure similar to that for 4. The Stille coupling reaction was performed to synthesize P1-**P6**. The number-average molecular weight (M_n) and polydispersity index (PDI) of these polymers were determined by GPC using polystyrene as standard and 1,2,4-trichlorobenzene as eluent at 135 °C. The data are listed in Table 1. The low M_n of **P1-P4** could be attributed to their poor solubility. Similar results were also observed in other TQ polymers.^{33, 34} After tuning the substitution positions and architectures of the side chains, P5 and P6 yielded much better degrees of polymerization and both exhibit excellent solubility in common solvents such as chloroform and tetrahydrofuran at room temperature. Additionally, all copolymers exhibited excellent thermal stability, with 5% weight loss up to 415 °C, measured by thermogravimetric analysis (TGA) (Figure S1 ESI).

Optical and Electrochemical Properties



Figure 3. UV-visible-NIR absorption spectra of **P1-P6** investigated in toluene solution (a) and in thin film (b).

UV-vis-NIR absorption spectra of the polymers were recorded in toluene solution as well as in thin films (Figure 3). The relevant data are summarized in Table 1. In dilute toluene solution, all polymers exhibit typical dual-band absorptions as other TQ polymers. The first one ranges from 300 to 600 nm and the second one covers from 650 to 1650 nm. The former band corresponds to the π - π * transition of the conjugated backbone, whereas the latter could be attributed to intramolecular charge transfer (ICT) between donor and acceptor within the polymer backbone.²⁵ It is worthy to mention that the intensity of the second absorption band of these polymers is close to the first ones, implying that these polymers possess strong ICT. Due to variable donor moieties of P1-P4, their absorption band edges exhibit significantly different red-shifts between 1200-1600 nm. The electron-donating ability of the donor moieties were estimated from their HOMO levels (Table S1), which were calculated using the density functional theory (DFT) with the B3LYP functional and 6-31 G* basis set.³⁵ The HOMO levels follow the order of T (-6.34 eV) <TT (-6.03 eV) \leq BT (-5.54 eV) \leq BDT (-5.47 eV). The HOMO energy of the TQ-2T moiety itself, however, is already higher lying with -5.02 eV since the two thiophenes already act as donor strongly raising the HOMO of unsubstituted PTQ (HOMO= - 6.08 eV) by more than 1 eV. Therefore the additional thiophene bridges and their different donor strength not influence the absorption band edges as often assumed.36 Much more important, therefore is the extend of conjugation in the combined molecules and that can already nicely be predicted by considering the HOMO and LUMO values of the monomeric subunits M1-M6 (Table S1). This can then explain why

Table 1. Molecular weights, optical absorption, electrochemical and OFET properties of P1-P6.

Polymers	Mn	PDI ^a	λ_{max} (nm)	λ_{max} (nm)	E_{g}^{opt}	IP	EA	μ_h , max., ave	$I_{\rm on}/I_{\rm off}$	$V_{\rm T}$
	(kg/mol) ^a		soln. b	film ^c	(eV) ^c	(eV) ^d	(eV) ^d	$(cm^2 V^{-1} s^{-1})$		(V)
P1	7.0	2.68	1140, 1330	1165	0.75	-4.95	-3.92	0.063, 0.046	~10	0
P2	5.4	2.15	1130, 1305	1135, 1313	0.81	-5.04	-3.99	0.081, 0.066	50-100	-2
P3	8.0	2.34	910-1090	916-1100	0.96	-5.28	-3.93	0.042, 0.033	100-150	-6
P4	9.1	2.33	975, 1160	962, 1169	0.94	-5.19	-3.94	0.10, 0.097	100-150	-1
P5	12.7	4.05	890, 1150	930, 1184	0.91	-5.21	-3.98	0.012, 0.007	100-150	-20
P6	18.8	3.48	900-1060	926, 1095	0.95	-5.23	-3.99	0.24, 0.19	$\sim 10^{4}$	-15

^aDetermined by GPC in 1,2,4-trichlorobenzene using polystyrene standards at 135 °C; ^bDissolved in toluene. ^cDrop-cast from toluene solution (2 mg/mL), $E_{opt} = 1240 \text{ nm}/\lambda_{onset}$. ^dIP and EA were estimated from the onsets of the first oxidation and reduction peaks, while the potentials were determined using ferrocene (Fc) as standard by empirical formulas IP/EA = - ($E_{Ox/Red onset}$ - $E_{Fc/Fc+(1/2)}$ +4.8) eV, wherein $E_{Fc/Fc+1/2} = 0.40 \text{ eV}$.

P1 and P2 show the longest wavelength absorptions followed by P4, P6=P3, and P5.

Compared to P4, P5 shows a blue-shift around 10 nm of the maximum wavelength (λ_{max}) and significant low molar extinction coefficient. The λ_{max} value of P6 reveals a blue shift of 100 nm in comparison with that of P4. These were related to different alkylation positions and architectures, which affected intramolecular interaction in polymer backbone, thereby changing the optical behavior of the TQ-2T polymers. On the other hand, P5 exhibits a long tail extending to 1500 nm, suggesting a high tendency to aggregate even in diluted solution.³⁷ This is in agreement with the high PDI of P5.

The films were prepared by drop-casting toluene solutions of these polymers onto glass slides. **P1-P6** displayed slightly broadened spectra but with only small red-shifts from 8 to 35 nm at λ_{max} compared with those in solution, indicating some aggregation in thin film. The optical band gaps calculated according to the absorption onset of the solid films are listed in Table 1. These results demonstrated that changing the donors and side chains can be effective for tuning the optical behavior of the polymers.



Figure 4. The reduction and oxidation curves of **P1-P6**. The films were deposited from chlorobenzene solutions.

The cyclic voltammetry was carried out to investigate the ionization potentials (IP) and electron affinities (EA) of the polymers.³⁸ The EA of three monomers **3**, **6** and **11** were also studied to clarify the influence of the side chains on the electron-withdrawing ability of the acceptors. The reduction curves of monomers are shown in Figure S2. The corresponding values of EA were calculated to be -3.77 -3.78 and -3.77 eV, according to the onset of the first reduction peak. These results implied that the number and architecture of the side chains grafted onto the **TQ-2T** core induce a very weak change in their electron-withdrawing ability. Figure 4 presents the reduction and oxidation curves of all **TQ-2T** copolymers. The corresponding data are calculated based on

the onset potentials and listed in Table 1. For **P1-P4**, we found that the IP values decreased gradually with the increased donor strength and this is also opposite tendency in contrast to other acceptors.^{36, 39, 40} This result implied that the significant difference in IP of **P1-P4** originated not only from different donors, but also from the conformation of the polymer backbone. Compared to IP, the slightly different EA of **P1-P4** was attributed to a dominant contribution of the same TQ core. The variation of the IP and EA values for **P4-P6** was very small. These results suggested that the adjustment of the substitution positions and architectures has a weak influence on IP and EA of the polymers, while variation of the donors in **P1-P4** bear a stronger effect on the IP of the polymers.

OFET Properties



Figure 5. Transfer (a), (c) and output (b), (d) curves of P4 and P6.

In order to evaluate the charge carrier transport of the polymers, OFET devices with bottom-gate bottom-contact architecture were fabricated onto the heavily doped silicon wafers with 300 nm thick thermally grown SiO₂ as the dielectric. The dielectric was functionalized by hexamethyldisilazane (HMDS) to minimize interfacial trapping sites. Au electrodes with 60 nm in thickness were evaporated, which act as the source and drain. All polymers were drop-casted from 2 mg/mL chlorobenzene solutions and subsequently annealed at 180 °C for 30 min to remove the residual solvent. The field-effect measurement was carried out under nitrogen atmosphere, and corresponding data including charge carrier mobilities (μ), current on/off ratios (I_{on}/I_{off}) and threshold voltages (V_T) are summarized in Table 1. The transistors of all polymers, **P1-P6**, only exhibit p-type field-effect behavior due to many thiophenes in the conjugated backbones. Indeed, weak donors like alkylated 2,5-

diethynylthiophene²⁶ and unsubstituted thiophene²⁷ combined with **PTQ** can be applied for ambipolar polymer semiconductors. The transfer and output characteristics of P4 and P6 are presented in Figure 5, while the plots of the other four polymers, P1-P3 and P5, are provided in ESI Figure S3. Among P1-P4, P4 showed the highest mobility of 0.1 cm² V⁻¹ s⁻¹ with an extremely low threshold voltage of -1 V. Due to the incorporation of the BDT unit, the transistor performance of P3 is significantly reduced with the mobility of 0.033 cm² V⁻¹ s⁻¹ and the threshold voltage of -6 V. In comparison to P3, P1 and P2 exhibited a minor improvement in hole transport with mobilities of 0.046 and 0.066 cm² \hat{V}^{-1} s⁻¹. Meanwhile their on/off ratio is lowered to $<10^2$. This behavior suggested that the donor segments play a crucial role in the charge carrier transport of TO polymers. P5 and P6 were designed and synthesized with higher molecular weight and increased solubility. Unfortunately, P5 showed a hole mobility approximately one order of magnitude lower than P4, most probably because of the increased torsion between the two neighboring thiophene units. Replacing four linear side chains on the TQ-2T core (P4) by a pair of branched ones as in P6 led to a dramatic improvement of the transistor performance with maximum hole mobility of 0.24 cm² V⁻¹ s⁻¹ and on/off ratio of 10^4 , although the threshold voltage is slightly increased to -15 V. This result proved that the substitution positions and architectures of the side chains critically affect the charge carrier transport in TO-2T-based polymers. The nonlinear behavior of the drain current (I_D) at low source-drain voltage (V_D) in the output characteristics of P4 and P6 was attributed to the contact resistance and charge injection limitation.⁴¹ Additionally, the relatively low on/off ratio of **P1-P6** might be related to adventitious doping, due to the high-lying IP of these polymers.^{42, 43} In spite of low on/off ratios for these polymers, it has to be emphasized that the reproducibility of OFET performances is relatively good. As shown in Table 2, the difference between maximum mobility and average value is only ranging from 3% to 27% for P1-P4 and P6. For P5, this difference is slightly increased to 41%.

Self-Organization in Bulk



Figure 6. 2DWAXS patterns of a) P1, b) P2, c) P3, d) P4, e) P5 and f) P6 (insets show the small-angle scattering range). Off-meridional reflections related to a preferential organization of the alkyl chains are indicated in b) and d) by dashed circles.

To understand the variation in device performance, two dimensional wide-angle X-ray scattering (2DWAXS) was used to investigate the molecular organization in bulk. The 2DWAXS measurements were performed on mechanical extruded fibers which were subsequently thermally annealed at 180 °C for 30 min. For the measurements, the fibers were mounted vertically towards the 2D detector and the scattering was recorded at 30 °C. The 2D patterns confirm slight variations between P1, P2, P5 and P3. Significant differences are observed for P4 and P6.

In the equatorial plane of the patterns reflections at small-angles are ascribed to the layer structure of conjugated polymer backbones oriented along the alignment direction of the fiber (Figure 6). The interlayer distance between lamellar structures of 3.06 nm for P1, 3.02 nm for P2 and 2.87 nm for P5 were determined from the main peak position. The scattering intensities on the meridional plane with d-spacing of 1.45 nm for P1, 1.65 nm for P2 and 1.85 nm for P5 are related to the length of a single repeat unit. These values are in agreement with the theoretical lengths of 1.46 nm for P1, 1.62 nm for P2 and 1.80 nm for P5 as calculated by Cerius² simulations.⁴⁴ More crucially, wide-angle equatorial scattering intensities are assigned to π -stacking distances of 0.38 nm for P1, 0.36 nm for P2 and 0.37 nm for P5. Additionally, the π -stacking reflection for P2 showed a slightly smaller full width at half maximum (FWHM)⁴⁵ than those for P1 and P5, indicating a larger coherence length along the stacking direction for P2. Table 2 summarizes the FWHM value and coherent length for the π -stacking direction for all investigated polymers. Interestingly, due to an improved overall crystallinity, the alkyl side chains of P2 exhibit a preferential ordered direction as evident from off-meridional reflections in the middle-angle region (dashed circles in Figure 6b). In contrast, the patterns for P1 and P5 display only a broad amorphous halo characteristic for disordered alkyl chains.

The interlayer distance of P3 compared to P1 and P2, however decreased to 2.80 nm, due to a slightly smaller backbone curvature, while a π -stacking distance of 0.36 nm is found. The amorphous halo related to a d-spacing of 0.45 nm is correlated also to the isotropic arrangement of alkyl chains. The interlayer distance observed for P4 and P6 is 3.03 nm and 2.94 nm, respectively. In comparison to the other polymers within this series, both compounds show more distinct π -stacking reflections corresponding to distances of 0.37 nm for P4 and 0.38 nm for P6. The variations in the interlayer and π stacking distance within this polymer series are due to the modifications in the backbone composition and substitution positions. A less planar donor unit in P4 and P6 in comparison to P2 and P3 increases the π -stacking distance. On the other hand, avoiding alkyl chains at the TQ acceptor and replacing the linear to branched alkyl chains for P6 slightly reduced the interlayer distance and increased the π -stacking distance. Surprisingly, at the same time the degree of order in P4 and P6 increased as evident from a higher coherence length π -stacking for both polymers in comparison to the other polymers (Table 2). Reflections in the off-meridional middleangle region corresponding to the d-spacings of 1.23 nm for P4 and 2.00 nm for P6 suggest that the repeat units of the polymer chains in neighbouring layers are shifted in the extrusion direction with respect to each other. Cerius² simulations confirmed this effect on the scattering pattern (Figure S4). In such organization P6 with branched alkyl chains and arranged in a more energetically favourable fashion. The shift is induced by the steric demand of the branched substituents allowing a more efficient space filling in the layer periphery. In this configuration, the donor units occupy positions adjacent to acceptor units in the neighboring layers. This packing of P6 induces higher crystallinity than for P1, P2, P3 and P5. Additional anisotropic off-meridional reflections for P4 corresponding to a d-spacing of 0.45 nm are assigned to alkyl chain ordering and confirm higher overall order in comparison to P1 and **P3**

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Table 2. Summary of the structural data of **P1-P6** from 2DWAXS. *FWHM* and coherence length have been calculated in the π -stacking direction.

Polymers	FWHM (°)	Coherence length (nm)	π-π spacing (nm)	Interlayer distance (nm)	
P1	4.7	1.7	0.38	3.06	
P2	3.1	2.6	0.36	3.02	
Р3	2.8	2.9	0.36	2.80	
P4	1.4	5.8	0.37	3.03	
P5	4.2	1.9	0.37	2.87	
P6	1.2	6.6	0.38	2.94	

For this polymer series, the charge carrier transport in field-effect transistors is insensitive on in the interlayer and π -stacking distance. It has been found that the coherence length in the π -stacking direction is more crucial for the electrical properties. In other words, a more ordered packing of the polymers chains in the layer structures ensures a more unhindered migration of charges as observed in the cases of **P4** and **P6**.

Conclusions

Six new TQ-2T-based polymers have been synthesized and characterized. Varying donor moieties, substitution positions and architectures of the alkyl chains in TQ-2T polymers can facilitate the tuning of the optoelectronic behavior, self-organization in bulk and charge carrier transport. Compared to P1-P3, P4 bears higher crystallinity leading to a hole mobility as high as 0.1 cm² V⁻¹ s⁻¹. Although P5 shows an enhanced solubility and molecular weight than P4, it produces a low crystallinity due to the increased torsion in the conjugated backbone and leads to therefore a low mobility of $0.007 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$. Interestingly, a pair of 2-decyltetradecyl chains used to replace the linear side chains does not significantly change the planarity of the polymers, but improves its molecular weight and solubility. Due to a higher coherence length in the π -stacking direction, the charge carrier mobility of P6 is increased up to 0.24 cm² V⁻¹ s⁻¹. The structure-property relationships of **TQ-2T**-polymers are beneficial to broaden the understanding of TQ-containing polymers and further design new TQ-polymers towards high performance.

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Notes and references

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